

# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

Eliyahou Harari, Robert D. Norman and Sanjay Mehrotra

Assignee:

SanDisk Corporation

Title:

Flash EEprom System

Serial No .:

**UNASSIGNED** 

Filing Date:

**HEREWITH** 

Docket No.:

11587 M-10187-43C US

Group Art Unit:

San Francisco, California

COMMISSIONER FOR PATENTS

Washington, D. C. 20231

#### PRELIMINARY AMENDMENT

Dear Sir:

Please amend the accompanying continuation application, concurrently with its filing, as follows:

#### IN THE SPECIFICATION:

## Page 1, between lines 3 and 4, insert the following:

### --Cross-Reference to Related Applications

This is a continuation of patent application serial no. 09/129,675, filed August 5, 1998, which is a continuation of patent application serial no. 08/771,708, filed December 20, 1996, now patent no. 5,991,517, which is a continuation of patent application serial no. 08/174,768, filed December 29, 1993, now patent no. 5,602,987, which is a continuation of patent application serial no. 07/963,838, filed October 20, 1992, now patent no. 5,297,148, which in turn is a division of patent application serial no. 07/337,566, filed April 13, 1989, abandoned .--

## Page 4, between lines 27 and 28, insert the following:

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-- The present invention also includes improvements in EEprom array read and write circuits and techniques in order to provide multiple threshold levels that allow accurate reading and writing of more than two distinct states within each memory cell over an extended lifetime of the memory cells, so that more than one bit may be reliably stored in each cell.

761800 v1 / PF-OA [Rev. 000913]